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Dock t Number (Optional)
81788.0251Application Number
Not Assigned; Parent 10/284,852**INFORMATION DISCLOSURE CITATION
IN AN APPLICATION**

(Use several sheets if necessary)

Applicant

FURUKAWA, et al.

Filing Date

June 23, 2003

Group Art Unit

Not Assigned

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
Gu	6,404,125	06-2002	Garbuzov et al.	313	499	
I	6,340,824	01-2002	Komoto et al.	257	99	
I	5,998,925	12-1999	Shimizu et al.	313	503	
Gu	5,813,752	09-1998	Singer et al.	362	293	

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO
	2000-082849	03/21/00	JAPAN				
	11-087778	03/30/99	JAPAN				
	10-012916	01/16/98	JAPAN				

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

	Thick GzN Epitaxial Growth with Low Dislocation Density by Hydride Vapor Phase Epitaxy – USUI, et al./ Japanese Journal of Applied Physics 36, Part 2, No. 7B, L899 (1997)

EXAMINER

G. M. [Signature]

DATE CONSIDERED

12/14/03

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.